

SANYO Semiconductors **DATA SHEET**

LA6541NH — For CD Players and Recorders Four-Channel Driver IC

Overview

The LA6541NH is a four-channel driver IC for CD players and recorders (four BTL amplifier channels).

Functions

- Four BTL connection power amplifier channels
- IO max 0.7A
- Built-in level shifters
- Muting circuit (on/off control of all outputs)
 (This circuit applies to the BTL amplifier circuits. It does not control operation of the regulator.)
- Built-in regulator (provides a 5V output using an external pnp transistor)
- Thermal protection circuit (thermal shutdown circuit)

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC} max		14	V
Maximum input voltage	VIN		13	V
Maximum output current	I _O max	For each of the channel 1 to 4 outputs	0.7	А
Muting pin application voltage	VMUTE		13	V
Allowable power dissipation	Pd max	Independent IC	0.8	W
		Specified circuit board	1.8	W
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

^{*} Specified substrate: 76.1mm×114.3mm×1.6mm, glass epoxy board.

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Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage 1	V _{CC} 1		5.6 to 13	V
Supply voltage 2	V _{CC} 2	Only used by the BTL amplifiers	3.9 to 13	V
		(Not used by the 5V regulator circuit)		

$\textbf{Electrical Characteristics} \ \ \text{at Ta} = 25^{\circ}\text{C}, \ V_{CC}1 = V_{CC}2 = 8\text{V}, \ VREF = 2.5\text{V}, \ unless \ otherwise specified}.$

Doromotor	Symbol	Conditions	Ratings			1.1-26
Parameter	Symbol	Conditions	min	typ	max	Unit
Overall Characteristics						
No-load current drain, on state	I _{CC} ON	All outputs on, MUTE : high		20	40	mA
No-load current drain, off state	I _{CC} OFF	All outputs off, MUTE : low		15	35	mA
Thermal shutdown circuit operating temperature	TSD	(Design guarantee value *1)	150	175	200	°C
Output Amplifier Block						
Output offset voltage	VOFF	The voltage difference between each of the + or - outputs.	-50		50	mV
VREF input voltage range	V _{IN} VREF		1.5		V _{CC} -1.5	V
Output voltage	Vo	The voltage across the outputs when $R_L = 8\Omega \label{eq:RL}$	4	4.7		V
Voltage gain, input to output	VG	The voltage gain from an input to the corresponding +/- outputs.*2		9		dB
Slew rate	SR	(Design guarantee value *1)		0.15		V/μs
Muting on voltage	VMUTE	The voltage at which the output on/off state changes		1.2		V
Power Supply Block (Using a 2S	B632K)					
5V power supply voltage		I _O = 200mA	4.75	5.00	5.25	V
Line regulation	ΔV _O LIN	5.6V ≤ V _{CC} ≤ 12V		20	100	mV
Load regulation	ΔV _O LOAD	5mA ≤ I _O ≤ 200mA		50	150	mV
Reset Block						
RESET pin high-level voltage	V _O RH		4.73	4.98	5.23	V
RESET pin low-level voltage	V _O RL	ISRL = 2mA, Cd-GND		100	200	mV
RESET pin threshold voltage	SET pin threshold voltage V _{RT} *4			4.2		V
RESET pin hysteresis	V _{HYS}	*5	40	100	200	mV
RESET pin output delay time	td	Cd = 0.1μF		10		ms

^{*1 :} These parameters are not tested.

^{*2 :} The gain from input to output when only the $V_{\mbox{\footnotesize{IN}}}{}^{\star}$ pins are used.

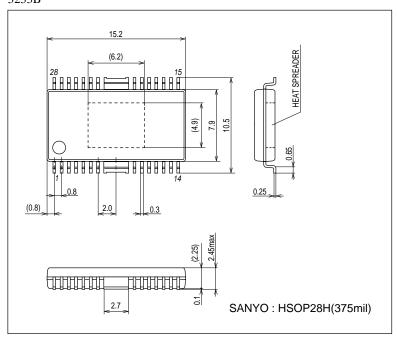
^{*3:} The MUTE pin voltage when the output changes between the on and off states. When the MUTE pin is high, all the BTL amplifiers will be on, and the when MUTE is low, all the BTL amplifiers will be off.

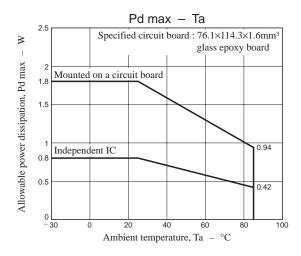
^{*4 :} The 5V regulator voltage when the RESET pin goes from high to low.

^{*5 :} The 5V regulator voltage difference between the RESET pin going from high to low the RESET pin going from low to high. That is, the hysteresis.

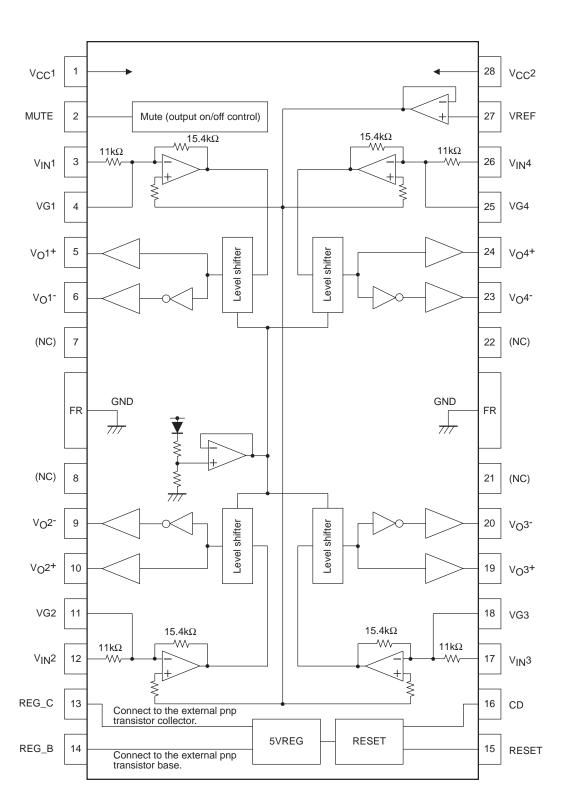
Package Dimensions

unit : mm (typ) 3233B





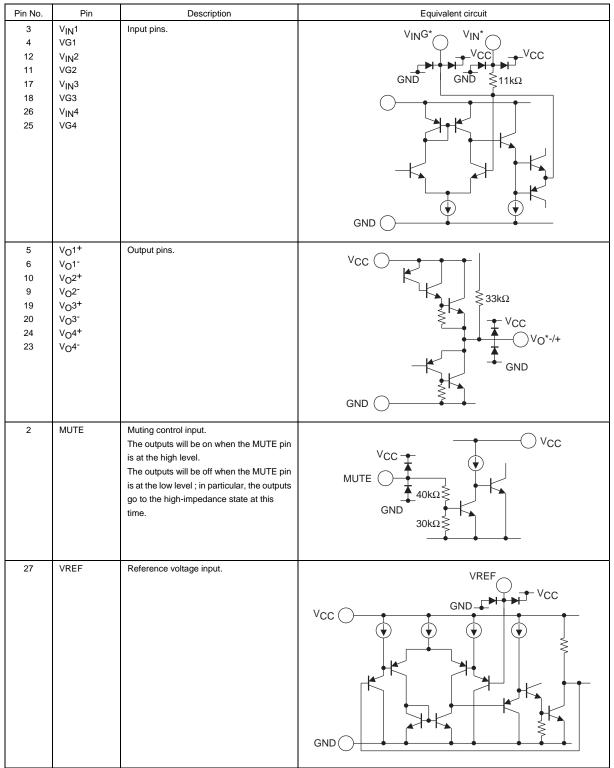
Block Diagram



Pin Functions

Pin No.	Pin	Description		
1	V _{CC} 1	Power supply (This pin is shorted to V _{CC} 2 (pin 28)		
2	MUTE	Output on/off control		
3	V _{IN} 1	Channel 1 input		
4	VG1	Channel 1 input (Gain setting)		
5	V _O 1+	Channel 1 output (+)		
6	V _O 1 ⁻	Channel 1 output (-)		
7	(NC)	(This pin must not be used.)		
8	(NC)	(This pin must not be used.)		
9	V _O 2 ⁻	Channel 2 output (-)		
10	V _O 2+	Channel 2 output (+)		
11	VG2	Channel 2 input (Gain setting)		
12	V _{IN} 2	Channel 2 input		
13	REG_C	Connect this pin to the external pnp transistor collector. (This is the 5 V regulator output)		
14	REG_B	Connect this pin to the external pnp transistor base.		
15	RESET	Reset output		
16	CD	Connection for the reset delay time setting capacitor		
17	V _{IN} 3	Channel 3 input (Gain setting)		
18	VG3	Channel 3 input (Gain setting)		
19	V _O 3+	Channel 3 output (+)		
20	V _O 3⁻	Channel 3 output (-)		
21	(NC)	(This pin must not be used.)		
22	(NC)	(This pin must not be used.)		
23	V _O 4 ⁻	Channel 4 output (-)		
24	V _O 4+	Channel 4 output (+)		
25	VG4	Channel 4 input (Gain setting)		
26	V _{IN} 4	Channel 4 input (Gain setting)		
27	VREF	Reference voltage input		
28	V _{CC} ²	Power supply (This pin is shorted to V _{CC} 1 (pin 1)		

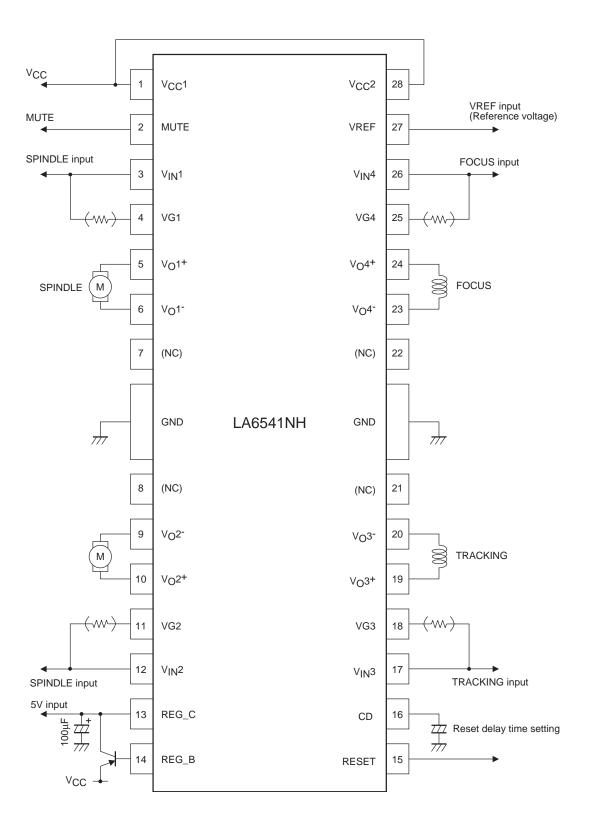
Equivalent Circuits



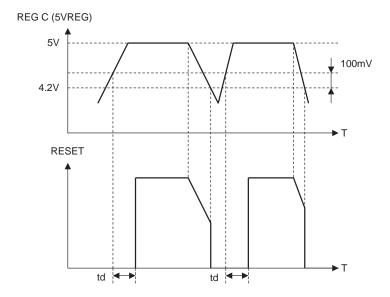
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Pin No.	Pin	Description	Equivalent circuit
15	RESET	Reset output. When REG C (5VREG) is high, RESET will be high. When REG C (5VREG) is low, RESET will be low. See section 11, Reset Operation, for details on the reset operation.	REG_C (5VREG) GND VCC RESET GND GND
16	CD	Reset output delay time setting. The delay time until the point the reset output switches from low to high is set by the capacitor connected between this pin and ground. See section 11, Reset Operation, for details on the reset operation.	GND CD GND

Application Circuit Example



Reset Operation



- *1: td is the delay time. It is set by an external capacitor connected between the CD pin and ground).
- *2 : The voltage at which RESET changes state is a typical value (voltage).

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